

60V P-Channel Enhancement Mode MOSFET

Voltage

-60 V

Current

-15 A

Features

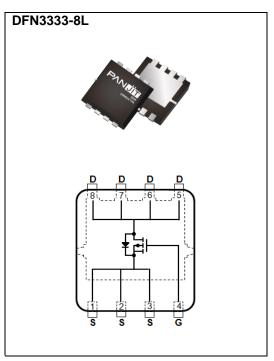
- R_{DS(ON)}, V_{GS}@-10V, I_D@-5A<48mΩ
- R_{DS(ON)}, V_{GS}@-4.5V, I_D@-3A<65mΩ
- High switching speed
- Low gate charge
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 Standard

Mechanical Data

• Case: DFN3333-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.03 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	-60	V	
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V	
Continuous Drain Current(Note 4)	Tc=25°C	I _D	-15		
	Tc=100°C		-10	А	
Pulsed Drain Current(Note 1)	Tc=25°C	I _{DM}	-60	<u> </u>	
Power Dissipation	Tc=25°C	Po	20	147	
	Tc=100°C		8	W	
Continuous Drain Current(Note 4)	T _A =25°C	Ι _D	-5		
	T _A =70°C		-4	Α	
Power Dissipation	T _A =25°C	Po	2	W	
	T _A =70°C		1.3		
Single Pulse Avalanche Energy ^(Note 6)		E _{AS}	51	mJ	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	R _{θJC}	6.3	°C/W	
	Junction to Ambient	R _{0JA}	62.5		

Limited only By Maximum Junction Temperature



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.7	-2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-5A	-	40	48	mΩ
		V _{GS} =-4.5V, I _D =-3A	-	55	65	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic ^(Note 7)						
Total Gate Charge	Q_g	V _{DS} =-30V, I _D =-5A, V _{GS} =-10V ^(Note 2,3)	-	22	-	nC
Gate-Source Charge	Q_gs		-	4.1	-	
Gate-Drain Charge	Q_{gd}		-	5.2	-	
Input Capacitance	Ciss	V _{DS} =-30V, V _{GS} =0V, f=1MHZ	-	1256	-	pF
Output Capacitance	Coss		-	87	-	
Reverse Transfer Capacitance	Crss		-	59	-	
Turn-On Delay Time	td _(on)	V_{DD} =-30V, I_{D} =-1A, V_{GS} =-10V, R_{G} =6 Ω (Note 2,3)	-	13	-	
Turn-On Rise Time	t _r		-	42	-	ns
Turn-Off Delay Time	td _(off)		-	65	-	
Turn-Off Fall Time	t _f		-	16	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	-15	А
Diode Forward Current	Is					
Diode Forward Voltage	V _{SD}	I _S =-1A, V _G S=0V	-	-0.7	-1	V

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. L=0.1mH, I_{AS} =-32A, V_{GS} =-10V, V_{DS} =-25V, R_{G} =25 ohm.
- 7. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

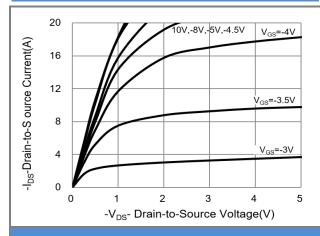


Fig.1 On-Region Characteristics

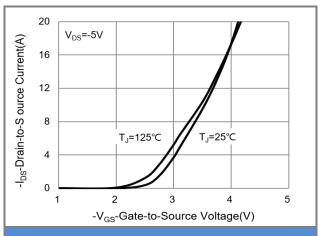


Fig.2 Transfer Characteristics

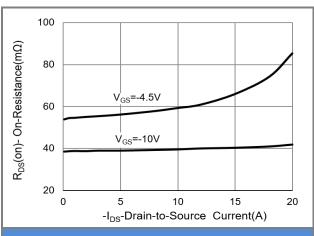


Fig.3 On-Resistance vs. Drain Current

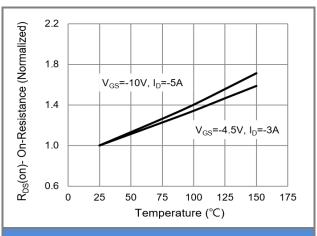
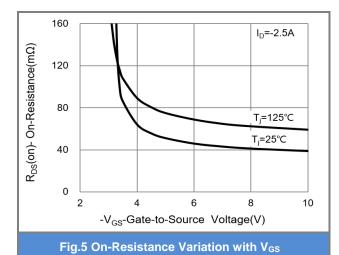


Fig.4 On-Resistance vs. Junction temperature



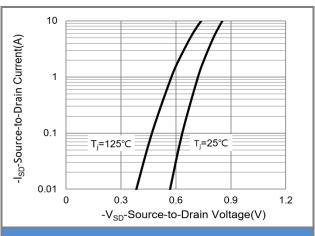


Fig.6 Source-Drain Diode Forward Voltage



TYPICAL CHARACTERISTIC CURVES

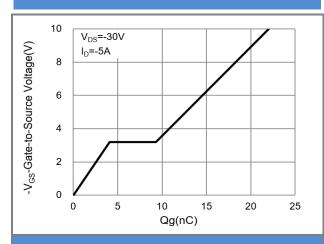


Fig.7 Gate-Charge Characteristics

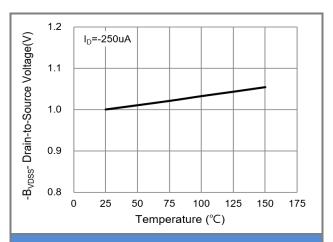


Fig.8 Breakdown Voltage Variation vs. Temperature

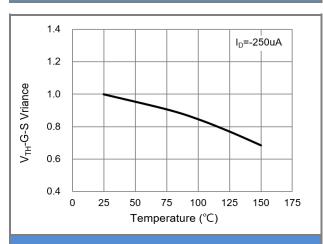


Fig.9 Threshold Voltage Variation with Temperature

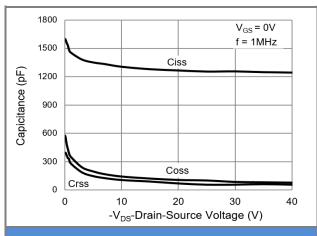


Fig.10 Capacitance vs. Drain-Source Voltage

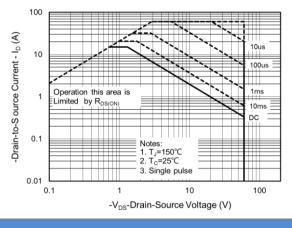


Fig.11 Maximum Safe Operating Area

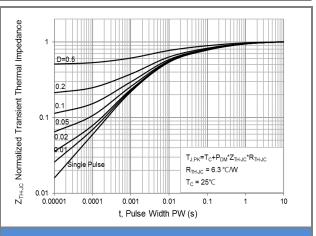


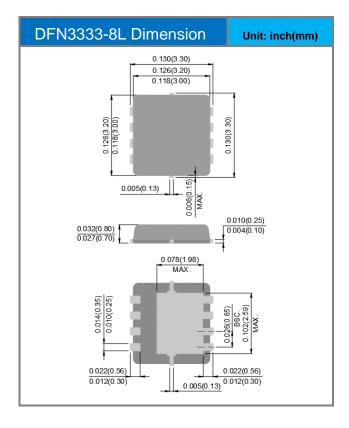
Fig.12 Normalized Transient Thermal Impedance

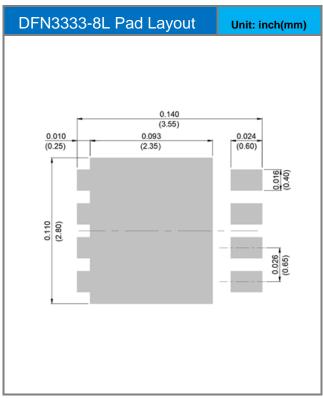


Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4465AP-AU_R2_000A1	DFN3333-8L	5K pcs / 13" reel	4465	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout







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